

N-Channel JFET, 15 V, 10 to 32 mA, 38 mS

NSVJ2394SA3

Automotive JFET designed for compact and efficient designs and including high gain performance. AEC-Q101 qualified JFET and PPAP capable suitable for automotive applications.

Features

- Large |yfs|
- Small Ciss
- This Small Package Enables Sets to be Smaller and Thinner
- Ultralow Noise Figure
- NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and PPAP Capable
- These Devices are Pb-Free and are RoHS Compliant

Applications

- AM Tuner RF Amplifier
- Low Noise Amplifier

Specifications

ABSOLUTE MAXIMUM RATINGS (at $T_A = 25^\circ\text{C}$)

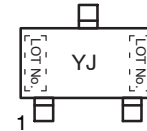
| Parameter | Symbol | Value | Unit |
|--|----------------|-------------|------------------|
| Drain-to-Source Voltage | V_{DSX} | 15 | V |
| Gate-to-Drain Voltage | V_{GDS} | -15 | V |
| Gate Current | I_G | 10 | mA |
| Drain Current | I_D | 50 | mA |
| Allowable Power Dissipation | P_D | 200 | mW |
| Operating Junction and Storage Temperature | T_J, T_{STG} | -55 to +150 | $^\circ\text{C}$ |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.



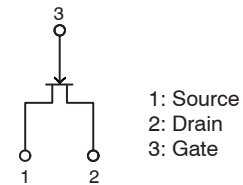
SC-59 / CP3
CASE 318BJ

MARKING DIAGRAM



YJ = Specific Device Code

ELECTRICAL CONNECTION



N-Channel

ORDERING INFORMATION

| Device | Package | Shipping [†] |
|----------------|------------------------|-----------------------|
| NSVJ2394SA3T1G | SC-59/CP3 (Pb-Free) | 3000 / Tape & Reel |

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

NSVJ2394SA3

ELECTRICAL CHARACTERISTICS (at $T_A = 25^\circ\text{C}$)

| Parameter | Symbol | Conditions | Min | Typ | Max | Unit |
|---------------------------------|---------------|---|------|------|------|------|
| Gate-to-Drain Breakdown Voltage | $V_{(BR)GDS}$ | $I_G = -10\ \mu\text{A}$, $V_{DS} = 0\ \text{V}$ | -15 | - | - | V |
| Gate Cutoff Current | I_{GSS} | $V_{GS} = -10\ \text{V}$, $V_{DS} = 0\ \text{V}$ | - | - | -1.0 | nA |
| Cutoff Voltage | $V_{GS(off)}$ | $V_{DS} = 5\ \text{V}$, $I_D = 100\ \mu\text{A}$ | -0.3 | -0.7 | -1.5 | V |
| Drain Current | I_{DSS} | $V_{DS} = 5\ \text{V}$, $V_{GS} = 0\ \text{V}$ | 10 | - | 32 | mA |
| Forward Transfer Admittance | $ y_{fs} $ | $V_{DS} = 5\ \text{V}$, $V_{GS} = 0\ \text{V}$, $f = 1\ \text{kHz}$ | 20 | 38 | - | mS |
| Input Capacitance | C_{iss} | $V_{DS} = 5\ \text{V}$, $V_{GS} = 0\ \text{V}$, $f = 1\ \text{MHz}$ | - | 10 | - | pF |
| Reverse Transfer Capacitance | C_{rss} | | - | 2.9 | - | pF |
| Noise Figure | NF | $V_{DS} = 5\ \text{V}$, $R_g = 1\ \text{k}\Omega$, $I_D = 1\ \text{mA}$, $f = 1\ \text{kHz}$ | - | 1.0 | - | dB |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

TYPICAL CHARACTERISTICS

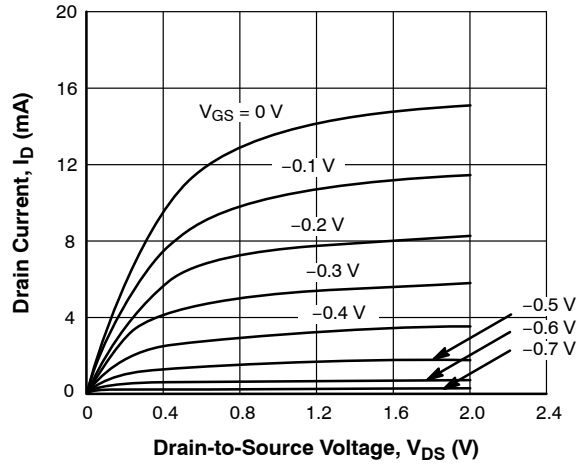


Figure 1. $I_D - V_{DS}$

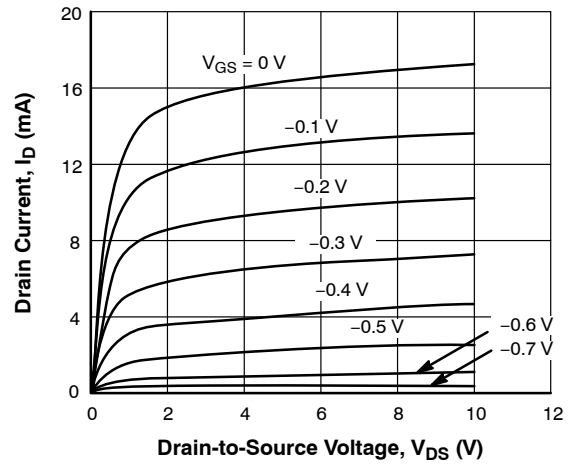


Figure 2. $I_D - V_{DS}$

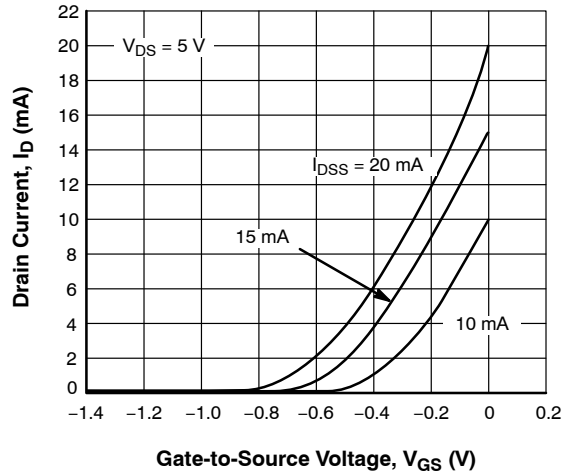


Figure 3. $I_D - V_{GS}$

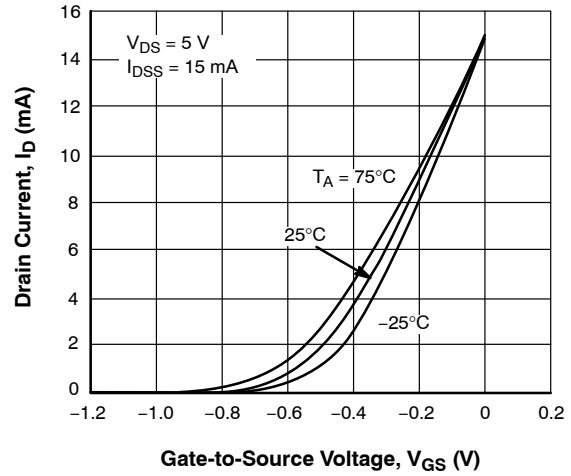


Figure 4. $I_D - V_{GS}$

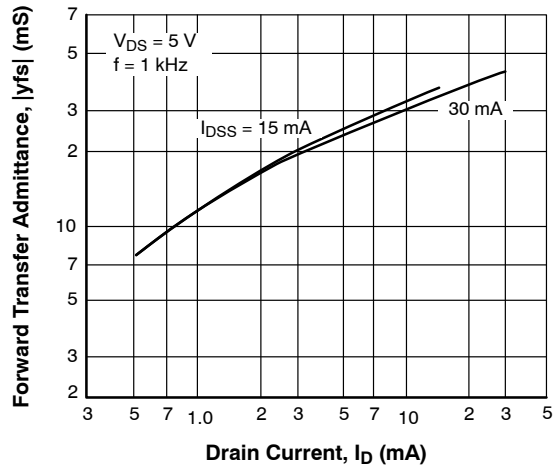


Figure 5. $|y_{fs}| - I_D$

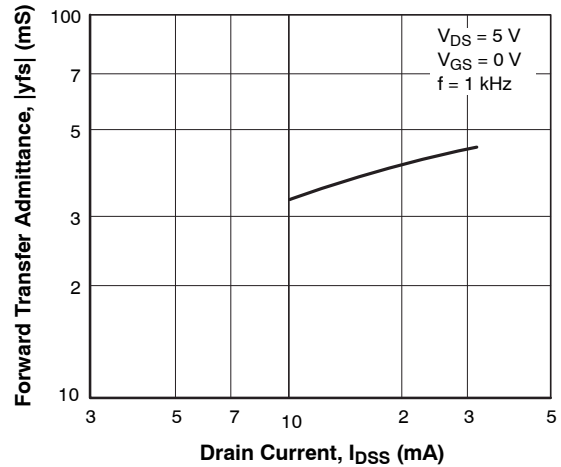


Figure 6. $|y_{fs}| - I_{DSS}$

TYPICAL CHARACTERISTICS (CONTINUED)

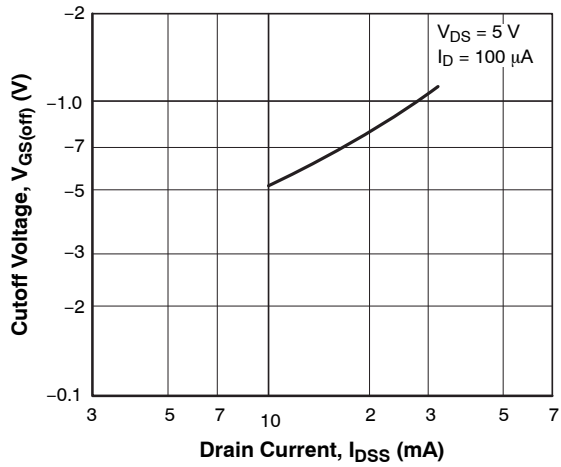


Figure 7. $V_{GS(off)} - I_{DSS}$

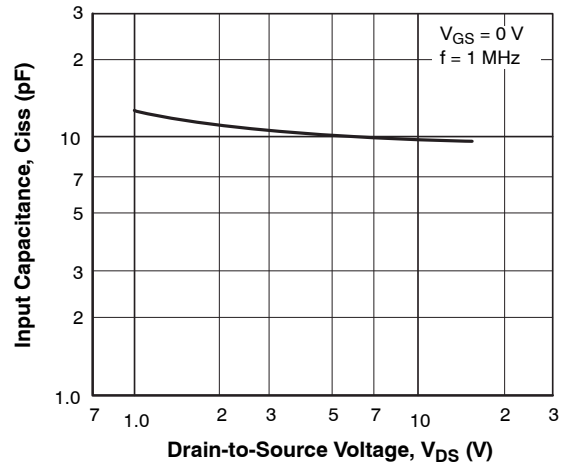


Figure 8. $C_{iss} - V_{DS}$

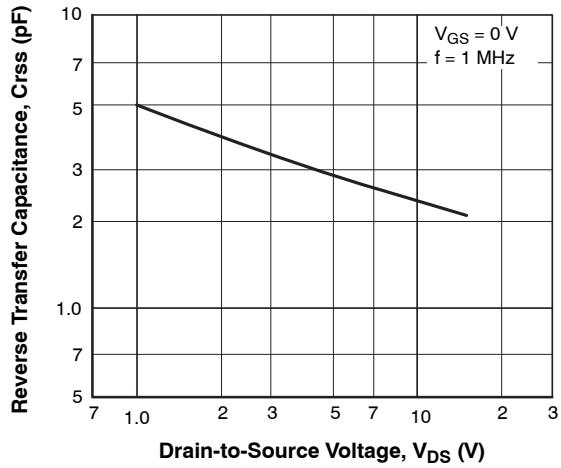


Figure 9. $C_{rss} - V_{DS}$

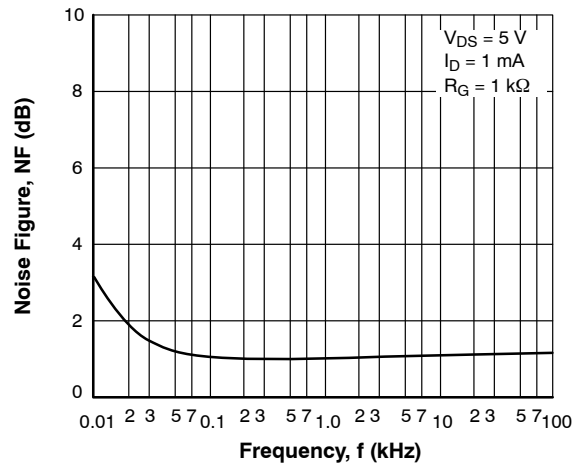


Figure 10. $NF - f$

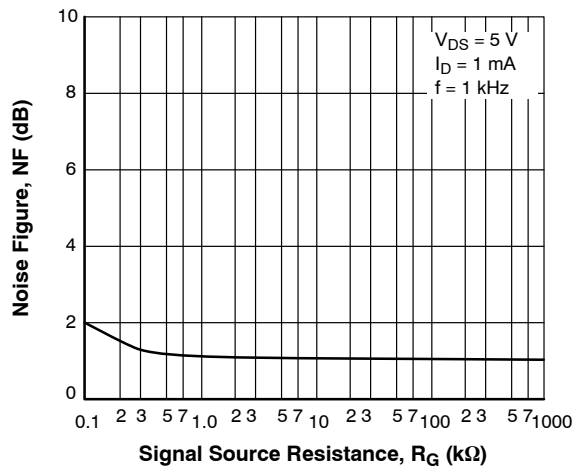


Figure 11. $NF - R_G$

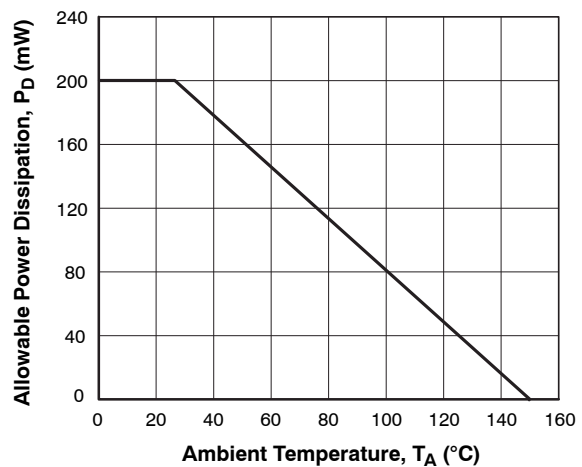


Figure 12. $P_D - T_A$

MECHANICAL CASE OUTLINE

PACKAGE DIMENSIONS

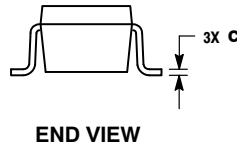
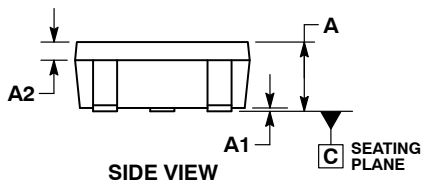
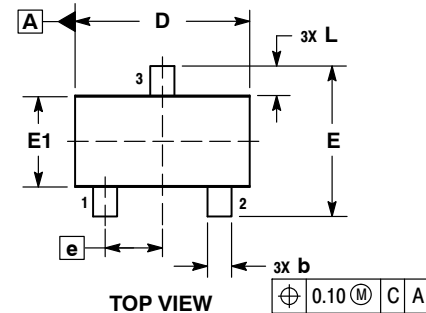
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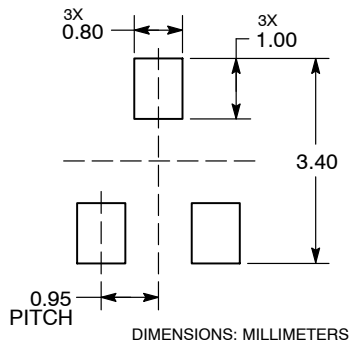
SCALE 2:1

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ISSUE O

DATE 09 JAN 2015



RECOMMENDED SOLDERING FOOTPRINT*

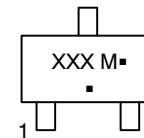


NOTES:

1. DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 1994.
2. CONTROLLING DIMENSION: MILLIMETERS.
3. DIMENSIONS D AND E1 DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS. MOLD FLASH, PROTRUSIONS, OR GATE BURRS SHALL NOT EXCEED 0.20 PER SIDE.
4. DIMENSIONS D AND E1 ARE MEASURED AT THE OUTERMOST EXTREME OF THE PLASTIC BODY.
5. DIMENSIONS b AND c APPLY TO THE FLAT SECTION OF THE LEAD BETWEEN 0.10 AND 0.20 FROM THE TIP.

| MILLIMETERS | | |
|-------------|----------|------|
| DIM | MIN | MAX |
| A | 0.95 | 1.35 |
| A1 | 0.00 | 0.10 |
| A2 | 0.20 | 0.40 |
| b | 0.35 | 0.50 |
| c | 0.10 | 0.20 |
| D | 2.75 | 3.05 |
| E | 2.30 | 2.70 |
| E1 | 1.35 | 1.65 |
| e | 0.95 BSC | |
| L | 0.35 | 0.75 |

GENERIC MARKING DIAGRAM



XXX = Specific Device Code
M = Date Code
▪ = Pb-Free Package

(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "▪", may or may not be present.

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

| | | |
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